

RD74LVC139B

Dual 2-to-4-line Decoders / Demultiplexers

REJ03D0503-0100

Rev.1.00

Dec. 02, 2004

Description

The RD74LVC139B has two independent two-to-four-line decoders each with a single active low enable input in a 16 pin package. Data on the select inputs cause one of the four normally high outputs to go low. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65 \text{ V}$ to 5.5 V
- All inputs $V_{IH} (\text{Max.}) = 5.5 \text{ V}$ ($@V_{CC} = 0 \text{ V}$ to 5.5 V)
- Typical V_{OL} ground bounce $< 0.8 \text{ V}$ ($@V_{CC} = 3.3 \text{ V}$, $T_a = 25^\circ\text{C}$)
- Typical V_{OH} undershoot $> 2.0 \text{ V}$ ($@V_{CC} = 3.3 \text{ V}$, $T_a = 25^\circ\text{C}$)
- High output current
 - $\pm 4 \text{ mA}$ ($@V_{CC} = 1.65 \text{ V}$)
 - $\pm 8 \text{ mA}$ ($@V_{CC} = 2.3 \text{ V}$)
 - $\pm 12 \text{ mA}$ ($@V_{CC} = 2.7 \text{ V}$)
 - $\pm 24 \text{ mA}$ ($@V_{CC} = 3.0 \text{ V}$ to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC139BFPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
RD74LVC139BTELL	TSSOP-16 pin	TTP-16DAV	T	ELL (2,000 pcs/reel)

Function Table

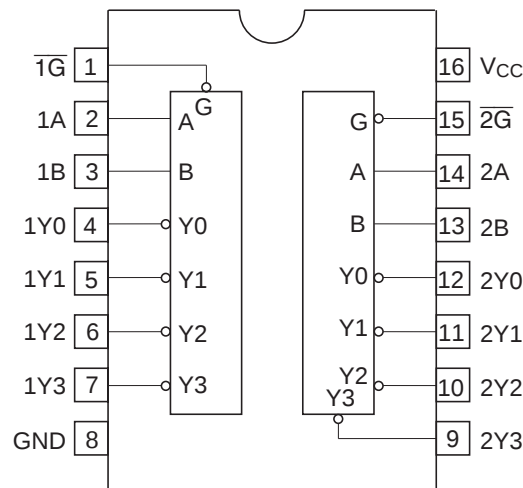
Input			Outputs			
Enable	Select					
G	B	A	Y0	Y1	Y2	Y3
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	L	H	H	L	H	H
L	H	L	H	H	L	H
L	H	H	H	H	H	L

H: High level

L: Low level

X: Immaterial

Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	-0.5 to 7.0	V	
Input diode current	I_{IK}	-50	mA	$V_I = -0.5\text{ V}$
Input voltage	V_I	-0.5 to 7.0	V	
Output diode current	I_{OK}	-50	mA	$V_O = -0.5\text{ V}$
		50		$V_O = V_{CC} + 0.5\text{ V}$
Output voltage	V_O	-0.5 to $V_{CC} + 0.5$	V	
Output current	I_O	± 50	mA	
V_{CC} , GND current / pin	I_{CC} or I_{GND}	100	mA	
Storage temperature	Tstg	-65 to 150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	1.5 to 5.5	V	Data retention
		1.65 to 5.5		At operation
Input / output voltage	V_I	0 to 5.5	V	$\bar{G}$, A, B
	V_O	0 to V_{CC}	V	Y0 to Y3
Operating temperature	T_a	-40 to 85	°C	
Output current	I_{OH}	-4	mA	$V_{CC} = 1.65\text{ V}$
		-8		$V_{CC} = 2.3\text{ V}$
		-12		$V_{CC} = 2.7\text{ V}$
		-24		$V_{CC} = 3.0\text{ V to }5.5\text{ V}$
	I_{OL}	4	mA	$V_{CC} = 1.65\text{ V}$
		8		$V_{CC} = 2.3\text{ V}$
		12		$V_{CC} = 2.7\text{ V}$
		24		$V_{CC} = 3.0\text{ V to }5.5\text{ V}$
Input rise / fall time ^{*1}	t_{r_i}, t_{f_i}	20	ns/V	$V_{CC} = 1.65\text{ V to }2.7\text{ V}$
		10		$V_{CC} = 3.0\text{ V to }5.5\text{ V}$

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

Item	Symbol	V _{CC} (V)	Ta = -40 to 85°C		Unit	Test Conditions
			Min	Max		
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.65	—	V	
		2.3 to 2.7	1.7	—		
		2.7 to 3.6	2.0	—		
		4.5 to 5.5	V _{CC} ×0.7	—		
	V _{IL}	1.65 to 1.95	—	V _{CC} ×0.35	V	
		2.3 to 2.7	—	0.7		
		2.7 to 3.6	—	0.8		
		4.5 to 5.5	—	V _{CC} ×0.3		
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} - 0.2	—	V	I _{OH} = -100 µA
		1.65	1.2	—		I _{OH} = -4 mA
		2.3	1.7	—		I _{OH} = -8 mA
		2.7	2.2	—		I _{OH} = -12 mA
		3.0	2.4	—		
		3.0	2.2	—		I _{OH} = -24 mA
		4.5	3.8	—		
	V _{OL}	1.65 to 5.5	—	0.2	V	I _{OL} = 100 µA
		1.65	—	0.45		I _{OL} = 4 mA
		2.3	—	0.7		I _{OL} = 8 mA
		2.7	—	0.4		I _{OL} = 12 mA
		3.0	—	0.55		I _{OL} = 24 mA
		4.5	—	0.55		
Input current	I _{IN}	0 to 5.5	—	±5.0	µA	V _{IN} = 5.5 V or GND
Quiescent supply current	I _{CC}	2.7 to 3.6	—	±5.0	µA	V _{IN} = 3.6 V to 5.5 V
		2.7 to 5.5	—	5.0		V _{IN} = V _{CC} or GND
	ΔI _{CC}	2.7 to 3.6	—	500	µA	V _{IN} = one input at (V _{CC} -0.6)V, other inputs at V _{CC} or GND

Switching Characteristics

Item	Symbol	V _{CC} (V)	Ta = -40 to 85°C			Unit	From (Input)	To (Output)
			Min	Typ	Max			
Propagation delay time	t _{PLH}	1.8±0.15	1.0	—	20.6	ns	A, B	Y0 to Y3
		2.5±0.2	1.0	—	9.3			
		2.7	1.0	—	7.3			
		3.3±0.3	1.0	—	6.2			
		5.0±0.5	1.0	—	5.5			
	t _{PHL}	1.8±0.15	1.0	—	19.5	ns	$\bar{G}$	Y0 to Y3
		2.5±0.2	1.0	—	7.2			
		2.7	1.0	—	5.2			
		3.3±0.3	1.0	—	4.7			
		5.0±0.5	1.0	—	4.5			
Output skew between pins*1	t _{OSLH}	1.8±0.15	—	—	—	ns		
		2.5±0.2	—	—	—			
		2.7	—	—	—			
		3.3±0.3	—	—	1.0			
		5.0±0.5	—	—	1.0			

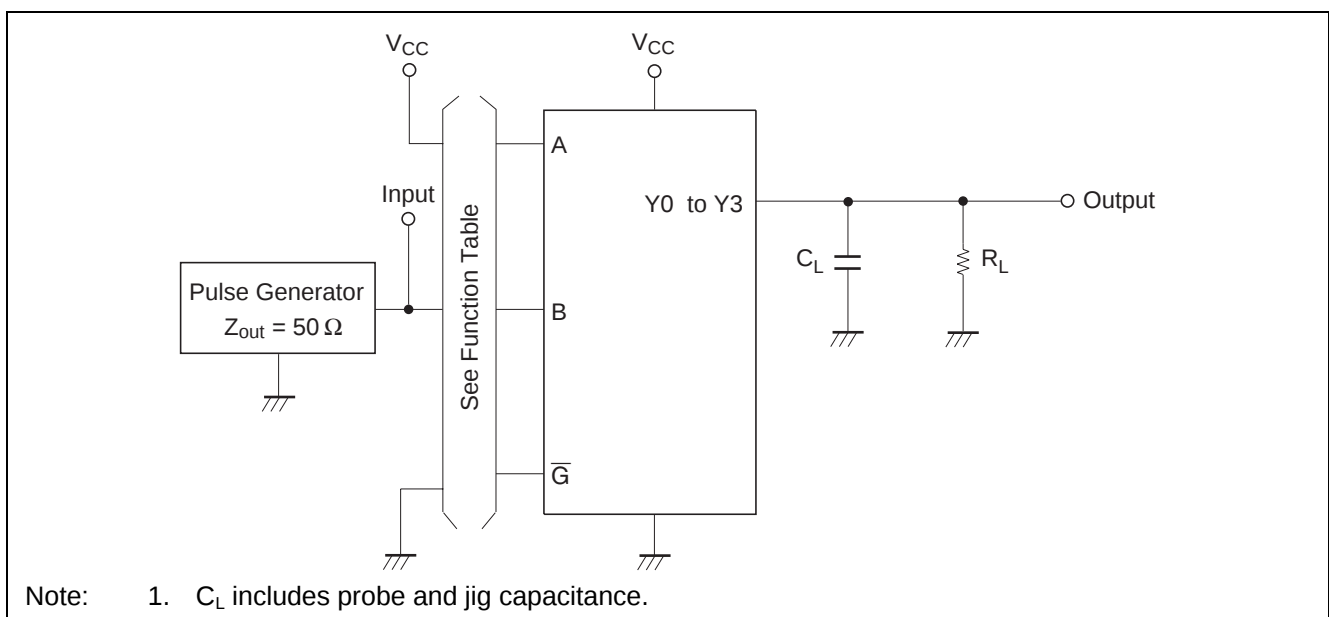
Note: 1. This parameter is characterized but not tested.

$$t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$$

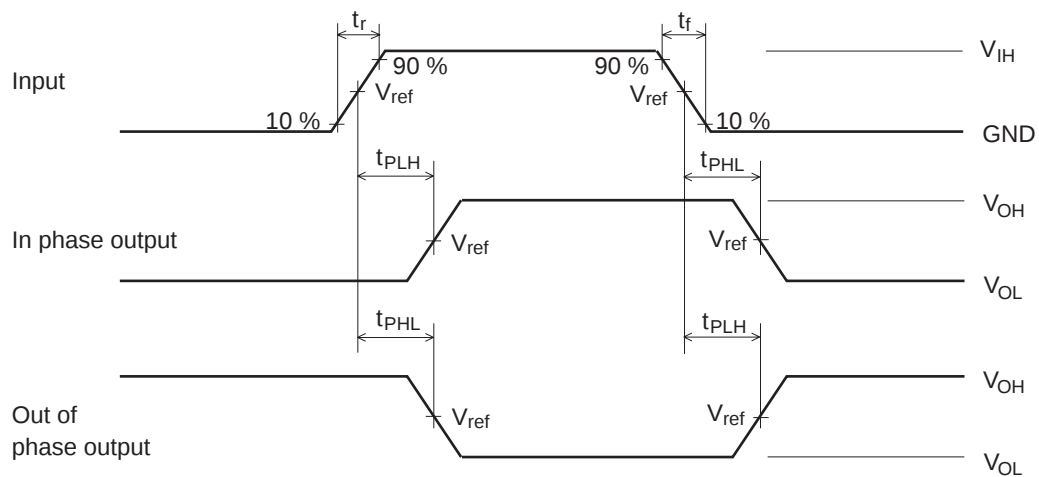
Operating Characteristics

Item	Symbol	V _{CC} = (V)	Ta = 25°C			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C _{PD}	1.8	—	28	—	pF	f = 10 MHz
		2.5	—	29	—		
		3.3	—	30	—		
		5.0	—	32	—		

Test Circuit



Waveforms



V_{CC} (V)	INPUTS		V_{ref}	C_L	R_L
	V_{IH}	t_r/t_f			
$V_{CC} = 1.8 \pm 0.15$ V	V_{CC}	≤ 2 ns	$1/2 V_{CC}$	30 pF	1.0 k Ω
$V_{CC} = 2.5 \pm 0.2$ V	V_{CC}	≤ 2 ns	$1/2 V_{CC}$	30 pF	500 Ω
$V_{CC} = 2.7$ V	2.7 V	≤ 2.5 ns	1.5 V	50 pF	500 Ω
$V_{CC} = 3.3 \pm 0.3$ V	2.7 V	≤ 2.5 ns	1.5 V	50 pF	500 Ω
$V_{CC} = 5.0 \pm 0.5$ V	V_{CC}	≤ 2.5 ns	$1/2 V_{CC}$	50 pF	500 Ω

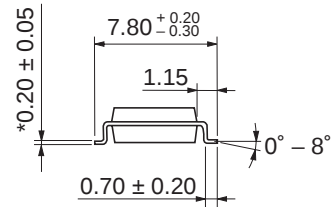
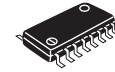
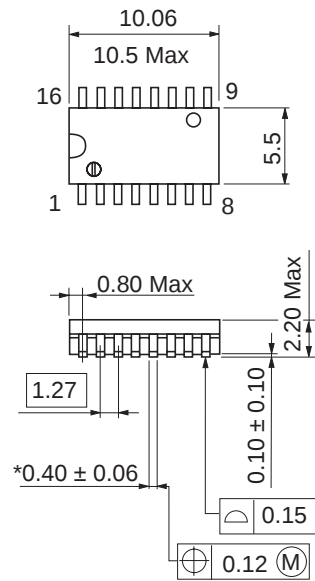
Note: 1. Input waveform: PRR = 10 MHz, duty cycle 50%

Package Dimensions

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As of January, 2003

Unit: mm

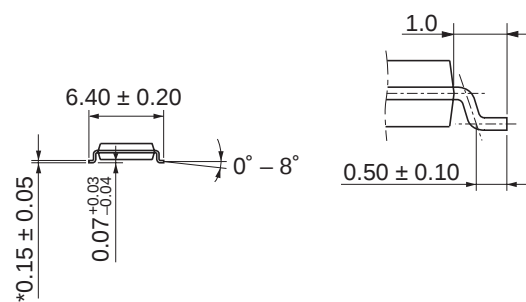
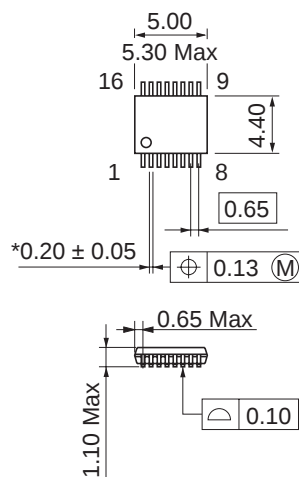


*Ni/Pd/Au plating

Package Code	FP-16DAV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.24 g

As of January, 2003

Unit: mm



*Ni/Pd/Au plating

Package Code	TTP-16DAV
JEDEC	—
JEITA	—
Mass (reference value)	0.05 g

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